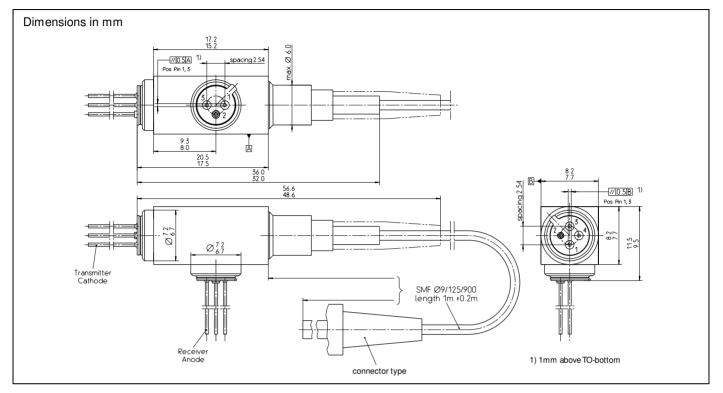


## MEDIUM POWER SBM 52214x BIDI® Optical Standard Module

1300 nm Emitting, 1300 nm Receiving





## FEATURES

- · Designed for application in passive-optical networks
- Integrated Wavelength Division Multiplexer (WDM) or Beam Splitter
- · Bi-Directional Transmission in one optical window
- · Single fiber solution
- FP-Laser Diode with Multi-Quantum Well structure
- Class 3B Laser Product
- · Suitable for bit rates up to 1 Gbit/s
- Ternary Photodiode at rear mirror for monitoring and control of radiant power
- · Low noise / high bandwidth PIN diode
- · Hermetically sealed subcomponents, similar to TO 46
- · With singlemode fiber pigtail

### **Absolute Maximum Ratings**

### Module

Operating temperature range at case, $T_C$
Laser Diode
Direct forward current, I <sub>F max</sub> 120 mA
Radiant power CW, P <sub>F, rad</sub> 2 mW
Reverse Voltage, V <sub>R</sub>
Monitor Diode
Reverse Voltage, V <sub>R</sub> 10 V
Forward Current, I <sub>F</sub> 2 mA
Receiver Diode
Reverse Voltage, V <sub>B</sub> 10 V
Forward Current, I <sub>F</sub>
Optical power into the optical port, P <sub>port</sub> 1.5 mW

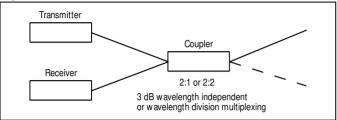
## DESCRIPTION

The Infineon module for bidirectional optical transmission has been designed for different optical networks structures:

In the last few years the structure has changed from point to point planned for Broad band ISDN to a point to multipoint passive optical network (PON) architecture for the optical network in the subscriber loop.

A transceiver can be realized with discrete elements (Fig. 1). Transmitter and receiver with pigtails are connected with a fiber-coupler (2:1 or 2:2, wavelength independent or WDM).

Figure 1. Realization with discrete elements

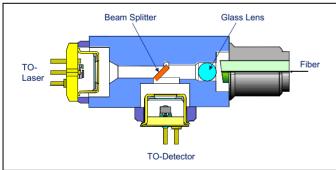


Infineon has realized this transceiver configuration in a compact module called a BIDI® (Fig. 2).

This module is especially suitable for separating the opposing signals at the ends of a link. It replaces a discrete solution with a transmitter, receiver and coupler.

The basic devices are a laser diode and a photodiode, each in a TO package, plus the filter in the beam path. A lens in the TO laser concentrates the light and enables it to be launched into the single-mode fiber of the module. In the same way the light from the fiber is focused onto the small, light-sensitive area of the photodiode to produce a high photo current. The mirror for coupling out the received signal is arranged in the beam so that the transmitter and receiver are at right angles to each other. This means the greatest possible degree of freedom in the layout of the electric circuit.

## Figure 2. Compact realization of the transceiver in one module



A decisive advantage of the module is its use of standard TO components. These devices, produced in large quantities, are hermetically sealed and tested before they are built in. This makes a very substantial contribution to the excellent reliability of the module. The solid metal package of the module serves the same purpose. It allows the use of modern laser welding techniques for reliable fixing of the different elements and the fiber holder.

## **TECHNICAL DATA**

The electro-optical characteristics described in the following tables are only valid for use within the specified maximum ratings or under the recommended operating conditions.

#### **Transmitter Electro-Optical Characteristics**

Parameter	Symbol	Min.	Тур.	Max.	Units
Optical output power (maximum)	P <sub>F, max</sub>	1.2			mW
Emission wavelength center of range P <sub>F</sub> =0.5 P <sub>F, max.</sub>	λ <sub>trans</sub>	1270		1350	nm
Spectral width (RMS)	$\sigma_{\lambda}$			5	
Temperature coeffi- cient of wavelength	TC			0.5	nm/K
Threshold current (whole temperature range)	l <sub>th</sub>	2		45	mA
Forward voltage P <sub>F</sub> =0.5 P <sub>F, max</sub> .	V <sub>F</sub>			1.5	V
Radiant power at I <sub>th</sub>	P <sub>th</sub>			50	μW
Slope efficiency (0+70°C)	η	20		100	mW/ A
Variation of 1st deriva- tive of P/I (0.1 to 1.0 mW)	S <sub>var</sub>	-30		30	%
Differential series resis- tance	R <sub>S</sub>			8	Ω
Rise and fall time (10%-90%)	t <sub>r</sub> , t <sub>f</sub>		0.5	1	ns

### **Monitor Diode Electro-Optical Characteristics**

Parameter	Symbol	Min.	Тур.	Max.	Units
Dark current, V <sub>R</sub> =5 V, P <sub>F</sub> =0, T=T <sub>max</sub>	I <sub>R</sub>			200	nA
Photocurrent, $V_R=5 V$ , $P_F=0.5 P_{F, max}$ .	Ι <sub>Ρ</sub>	50		1500	μA
Capacitance, V <sub>R</sub> =5 V, f=1 MHz	C <sub>5</sub>			10	pF
Tracking error <sup>(1)</sup> , V <sub>R</sub> =5 V	TE	-1		1	dB

Note

1. The tracking error TE is the maximum deviation of P<sub>F</sub> at constant current I<sub>mon</sub> over a specified temperature range and relative to the reference point: I<sub>mon,ref</sub>=I<sub>mon</sub> (T=25°C, P<sub>F</sub>=0.5 P<sub>F, max.</sub>). Thus, TE is given by:

TE [dB] = 10 x log 
$$\frac{P_F [Tc]}{P_F [25^{\circ}C]}$$

#### **Receiver Diode Electro-Optical Characteristics**

Parameter	Symbol	Min.	Тур.	Max.	Units
Spectral sensitivity $V_R=5 V$ , $\lambda=1300 \text{ nm}$	S <sub>rec</sub>	0.3		1	A/W
Rise and fall time (10%–90%) R <sub>L</sub> =50 Ω, V <sub>R</sub> =5 V	t <sub>r</sub> ; t <sub>f</sub>			1	ns
Total capacitance V <sub>R</sub> =5 V, P <sub>opt</sub> =0, f=1 MHz	С			1.5	pF
Dark current V <sub>R</sub> =5 V, P <sub>opt</sub> =0	I <sub>D</sub>			50	nA

#### **Module Electro-Optical Characteristics**

Parameter	Symbol	Min.	Тур.	Max.	Units
Optical Crosstalk <sup>(1)</sup>	CRT			-22	dB

#### Note

1. Optical Crosstalk is defined as

CRT [dB] = 10 x log  $\frac{I_{Det.o}}{I_{Det.1}}$ 

with:

 $I_{Det,0}$  : the photocurrent with P\_F=0.5 P\_{F,\,max.}, without optical input, CW laser operation, V\_R=2 V and

 $I_{Det,1}$  : the photocurrent without  $P_F$  but 0.5  $P_{F,\mbox{ max.}}$  optical input power,  $\lambda{=}\,1300$  nm.

## End of Life Time Characteristics

Parameter	Symbol	Min.	Тур.	Max.	Units
Threshold current at T=T <sub>max</sub>	l <sub>th</sub>			60	mA
Current above threshold, over full temperature range, at $I_{mon,ref}=I_{mon}$ (T=25°C, $P_{F}=0.5 P_{F, max.}$ , BOL)	ΔI <sub>F</sub>	7		70	
Tracking Error	TE	-1.5		1.5	dB
Detector Dark Current, V <sub>R</sub> =2 V, T=T <sub>max</sub>	I <sub>R</sub>			400	nA
Monitor Dark Current, V <sub>R</sub> =2 V, T=T <sub>max</sub>	I <sub>R</sub>			1	μA

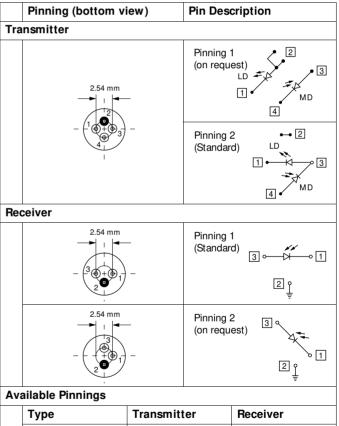
## **FIBER DATA**

The mechanical fiber characteristics are described in the follow-ing table.

#### **Fiber Characteristics**

Parameter	Min.	Тур.	Max.	Units
Mode Field Diameter	8	9	10	μm
Cladding Diameter	123	125	127	
Mode Field/Cladding Concentricity Error			1	
Cladding Non-circularity			2	%
Mode Field Non-circularity			6	
Cut off Wavelength	1270			nm
Jacket Diameter	0.8		1	mm
Bending Radius	30			
Tensile Strength Fiber Case	5	1		Ν
Length	0.8		1.2	m

#### **Pin Description**



Туре	Transmitter	Receiver	
SBM 52214x	2	1	
SBM51214x	1 (on request)	1 (on request)	
	Other Pinnings on request		

#### **Regulatory Compliance**

Feature	Standard	Comments
Electrostatic Discharge (ESD) to the Electrical Pins	MIL-STD 883C Method 3015.7	Class 1 (<500 V)

#### EYE SAFETY

Ensure to avoid exposure of human eyes to high power laser diode emitted laser beams. Especially do not look directly into the laser diode or the collimated laser beam when the diode is activated.

## CLASS 3B LASER PRODUCT according to IEC 60825-1

Required Labels



# Class IIIb LASER PRODUCT according to FDA Regulations complies with 21 CFR 1040.10 and 1040.11

#### **Required Label**



#### Laser Data

Wavelength	1300 nm
Maximum total output power	less than 50 mW
Beam divergence (1/e <sup>2</sup> )	10°

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#### Attention please!

The information herein is given to describe certain components and shall not be considered as warranted characteristics.

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#### Information

For further information on technology, delivery terms and conditions and prices please contact the Infineon Technologies offices or our Infineon Technologies Representatives worldwide - see our webpage at **www.infineon.com/fiberoptics** 

#### **CONNECTOR OPTIONS**

Model	Connector	Туре
SBM52214G SBM51214G		SM FC/PC
SBM 52214N SBM 51214N	I RIE am	SM SC/PC 0°
SBM52214Z SBM51214Z		without connector

#### Warnings

Due to technical requirements components may contain dangerous substances. For information on the types in question please contact your Infineon Technologies offices.

Infineon Technologies Components may only be used in life-support devices or systems with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system, or to affect the safety or effectiveness of that device or system. Life support devices or systems are intended to be implanted in the human body, or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.